

# Thyristor

$$V_{RRM} = 1400\text{ V}$$

$$I_{TAV} = 30\text{ A}$$

$$V_T = 1.3\text{ V}$$

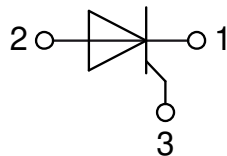
## Single Thyristor

Part number

**CS30-14io1**



Backside: anode



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

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| Thyristor      |  |  | Ratings                         |      |      |                  |
|----------------|--|--|---------------------------------|------|------|------------------|
| Symbol         | Definition   | Conditions   | min.                            | typ. | max. | Unit             |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}C$   |                                 |      | 1500 | V                |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^{\circ}C$   |                                 |      | 1400 | V                |
| $I_{RD}$       | reverse current, drain current                       | $V_{R/D} = 1400\text{ V}$  | $T_{VJ} = 25^{\circ}C$          |      | 50   | $\mu A$          |
|                |  | $V_{R/D} = 1400\text{ V}$  | $T_{VJ} = 125^{\circ}C$         |      | 2    | mA               |
| $V_T$          | forward voltage drop                                 | $I_T = 30\text{ A}$  | $T_{VJ} = 25^{\circ}C$          |      | 1.30 | V                |
|                |  | $I_T = 60\text{ A}$  |                                 |      | 1.63 | V                |
|                |  | $I_T = 30\text{ A}$  | $T_{VJ} = 125^{\circ}C$         |      | 1.30 | V                |
|                |  | $I_T = 60\text{ A}$  |                                 |      | 1.71 | V                |
| $I_{TAV}$      | average forward current                              | $T_C = 120^{\circ}C$   | $T_{VJ} = 150^{\circ}C$         |      | 30   | A                |
| $I_{T(RMS)}$   | RMS forward current                                  | 180° sine  |                                 |      | 47   | A                |
| $V_{T0}$       | threshold voltage                                    | } for power loss calculation only  | $T_{VJ} = 150^{\circ}C$         |      | 0.87 | V                |
| $r_T$          | slope resistance                                     |  |                                 |      | 14.2 | m $\Omega$       |
| $R_{thJC}$     | thermal resistance junction to case                  |  |                                 |      | 0.5  | K/W              |
| $R_{thCH}$     | thermal resistance case to heatsink                  |  |                                 | 0.3  |      | K/W              |
| $P_{tot}$      | total power dissipation                              |  | $T_C = 25^{\circ}C$             |      | 250  | W                |
| $I_{TSM}$      | max. forward surge current                           | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$   | $T_{VJ} = 45^{\circ}C$          |      | 400  | A                |
|                |  | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$  | $V_R = 0\text{ V}$              |      | 430  | A                |
|                |  | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$   | $T_{VJ} = 150^{\circ}C$         |      | 340  | A                |
|                |  | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$  | $V_R = 0\text{ V}$              |      | 365  | A                |
| $I^2t$         | value for fusing                                     | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$   | $T_{VJ} = 45^{\circ}C$          |      | 800  | A <sup>2</sup> s |
|                |  | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$  | $V_R = 0\text{ V}$              |      | 770  | A <sup>2</sup> s |
|                |  | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$   | $T_{VJ} = 150^{\circ}C$         |      | 580  | A <sup>2</sup> s |
|                |  | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$  | $V_R = 0\text{ V}$              |      | 555  | A <sup>2</sup> s |
| $C_J$          | junction capacitance                                 | $V_R = 400\text{ V } f = 1\text{ MHz}$   | $T_{VJ} = 25^{\circ}C$          |      | 16   | pF               |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30\text{ }\mu s$  | $T_C = 150^{\circ}C$            |      | 10   | W                |
|                |  | $t_p = 300\text{ }\mu s$   |                                 |      | 5    | W                |
| $P_{GAV}$      | average gate power dissipation                       |  |                                 |      | 0.5  | W                |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 125^{\circ}C; f = 50\text{ Hz}$  | repetitive, $I_T = 90\text{ A}$ |      | 150  | A/ $\mu s$       |
|                |  | $t_p = 200\text{ }\mu s; di_G/dt = 0.3\text{ A}/\mu s;$                                  | non-repet., $I_T = 30\text{ A}$ |      | 500  | A/ $\mu s$       |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V = \frac{2}{3} V_{DRM}$  | $T_{VJ} = 125^{\circ}C$         |      | 1000 | V/ $\mu s$       |
|                |  | $R_{GK} = \infty; \text{ method 1 (linear voltage rise)}$                                |                                 |      |      |                  |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6\text{ V}$   | $T_{VJ} = 25^{\circ}C$          |      | 1    | V                |
|                |  |  | $T_{VJ} = -40^{\circ}C$         |      | 1.2  | V                |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6\text{ V}$   | $T_{VJ} = 25^{\circ}C$          |      | 55   | mA               |
|                |  |  | $T_{VJ} = -40^{\circ}C$         |      | 80   | mA               |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$  | $T_{VJ} = 125^{\circ}C$         |      | 0.2  | V                |
| $I_{GD}$       | gate non-trigger current                             |  |                                 |      | 5    | mA               |
| $I_L$          | latching current                                     | $t_p = 10\text{ }\mu s$  | $T_{VJ} = 25^{\circ}C$          |      | 150  | mA               |
|                |  | $I_G = 0.3\text{ A}; di_G/dt = 0.3\text{ A}/\mu s$                                       |                                 |      |      |                  |
| $I_H$          | holding current                                      | $V_D = 6\text{ V } R_{GK} = \infty$  | $T_{VJ} = 25^{\circ}C$          |      | 100  | mA               |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$  | $T_{VJ} = 25^{\circ}C$          |      | 2    | $\mu s$          |
|                |  | $I_G = 0.3\text{ A}; di_G/dt = 0.3\text{ A}/\mu s$                                       |                                 |      |      |                  |
| $t_q$          | turn-off time  | $V_R = 100\text{ V}; I_T = 30\text{ A}; V = \frac{2}{3} V_{DRM}$                         | $T_{VJ} = 125^{\circ}C$         |      | 150  | $\mu s$          |
|                |  | $di/dt = 15\text{ A}/\mu s \quad dv/dt = 20\text{ V}/\mu s \quad t_p = 200\text{ }\mu s$ |                                 |      |      |                  |



| Package TO-247 |                              |              | Ratings |      |      |      |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions   | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal |         |      | 70   | A    |
| $T_{VJ}$       | virtual junction temperature |              | -40     |      | 150  | °C   |
| $T_{op}$       | operation temperature        |              | -40     |      | 125  | °C   |
| $T_{stg}$      | storage temperature          |              | -40     |      | 150  | °C   |
| <b>Weight</b>  |                              |              |         | 6    |      | g    |
| $M_D$          | mounting torque              |              | 0.8     |      | 1.2  | Nm   |
| $F_C$          | mounting force with clip     |              | 20      |      | 120  | N    |

**Product Marking**



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | CS30-14io1      | CS30-14io1         | Tube          | 30       | 466573   |

| Similar Part | Package      | Voltage class |
|--------------|--------------|---------------|
| CS30-12io1   | TO-247AD (3) | 1200          |
| CS30-16io1   | TO-247AD (3) | 1600          |

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$



**Thyristor**

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.87 | V  |
| $R_{0\ max}$ | slope resistance * | 11.7 | mΩ |



**Outlines TO-247**



| Sym. | Inches    |       | Millimeter |       |
|------|-----------|-------|------------|-------|
|      | min.      | max.  | min.       | max.  |
| A    | 0.185     | 0.209 | 4.70       | 5.30  |
| A1   | 0.087     | 0.102 | 2.21       | 2.59  |
| A2   | 0.059     | 0.098 | 1.50       | 2.49  |
| D    | 0.819     | 0.845 | 20.79      | 21.45 |
| E    | 0.610     | 0.640 | 15.48      | 16.24 |
| E2   | 0.170     | 0.216 | 4.31       | 5.48  |
| e    | 0.215 BSC |       | 5.46 BSC   |       |
| L    | 0.780     | 0.800 | 19.80      | 20.30 |
| L1   | -         | 0.177 | -          | 4.49  |
| Ø P  | 0.140     | 0.144 | 3.55       | 3.65  |
| Q    | 0.212     | 0.244 | 5.38       | 6.19  |
| S    | 0.242 BSC |       | 6.14 BSC   |       |
| b    | 0.039     | 0.055 | 0.99       | 1.40  |
| b2   | 0.065     | 0.094 | 1.65       | 2.39  |
| b4   | 0.102     | 0.135 | 2.59       | 3.43  |
| c    | 0.015     | 0.035 | 0.38       | 0.89  |
| D1   | 0.515     | -     | 13.07      | -     |
| D2   | 0.020     | 0.053 | 0.51       | 1.35  |
| E1   | 0.530     | -     | 13.45      | -     |
| Ø P1 | -         | 0.29  | -          | 7.39  |



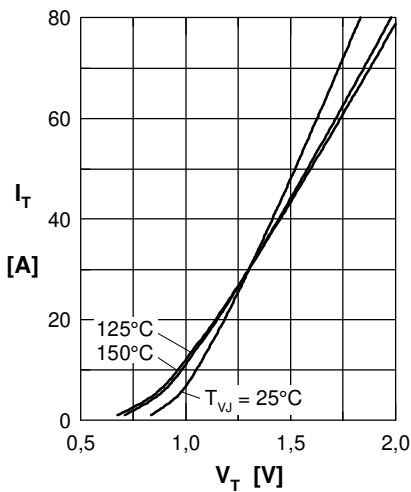
**Thyristor**


Fig. 1 Forward characteristics

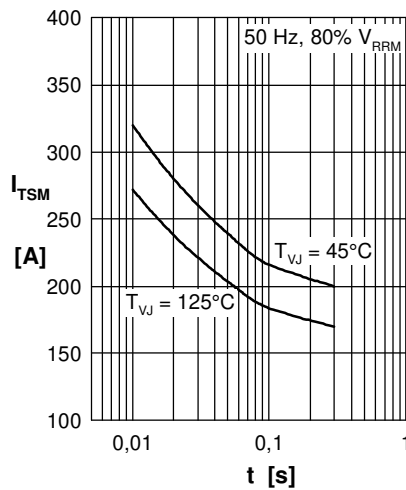


Fig. 2 Surge overload current

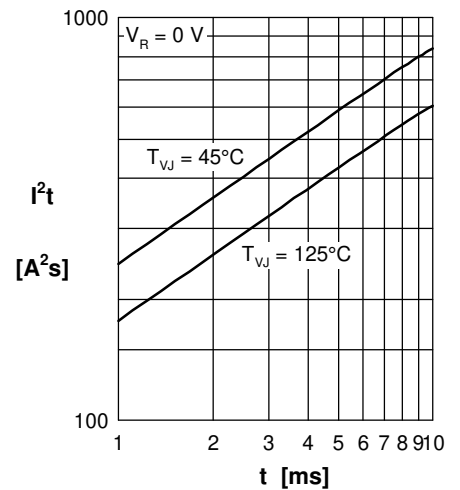
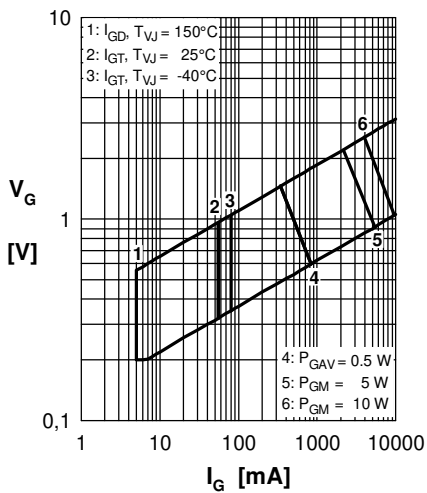

 Fig. 3  $I^2t$  versus time (1-10 ms)


Fig. 4 Gate trigger characteristics

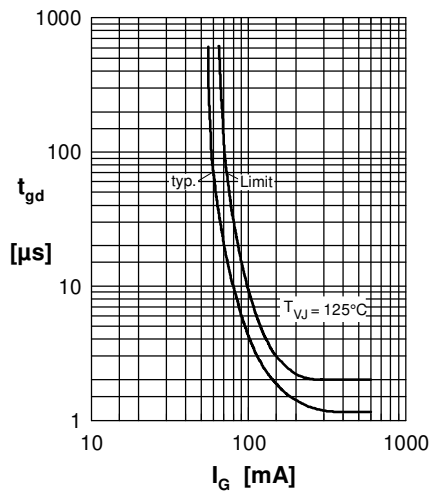


Fig. 5 Gate controlled delay time

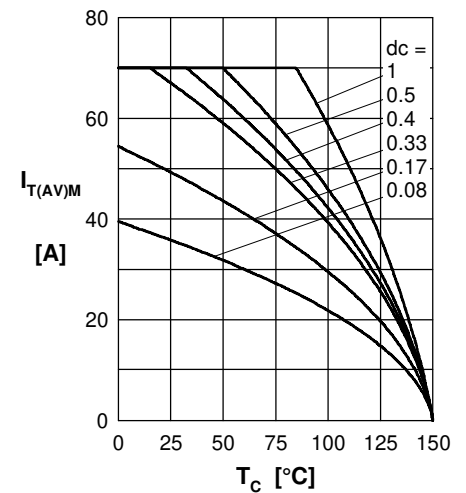


Fig. 6 Max. forward current at case temperature

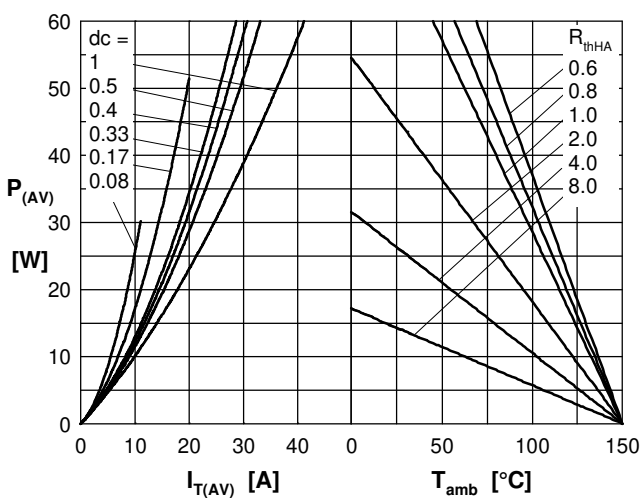
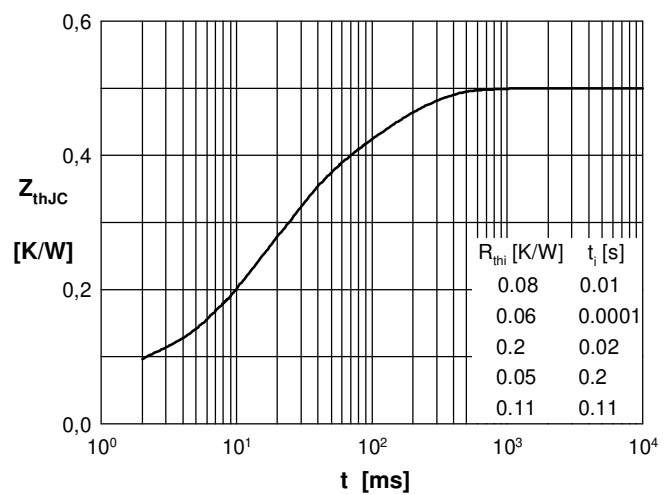

 Fig. 7a Power dissipation versus direct output current  
 Fig. 7b and ambient temperature


Fig. 8 Transient thermal impedance junction to case

